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International
IOR Rectifier

Data Sheet No. PD60173 rev.H

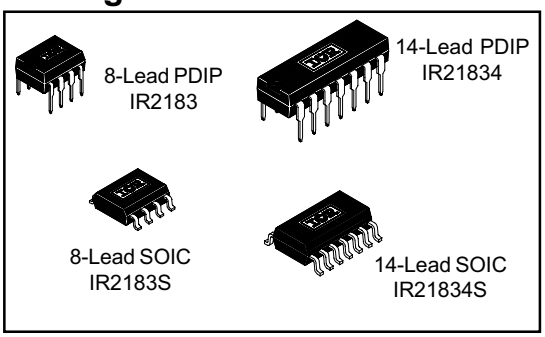
IR2183(4)(S)&(PbF)

HALF-BRIDGE DRIVER

Features

- Floating channel designed for bootstrap operation
  - Fully operational to +600V
  - Tolerant to negative transient voltage
  - dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout for both channels
- 3.3V and 5V input logic compatible
- Matched propagation delay for both channels
- Logic and power ground +/- 5V offset.
- Lower di/dt gate driver for better noise immunity
- Output source/sink current capability 1.4A/1.8A
- Also available LEAD-FREE (PbF)

Packages



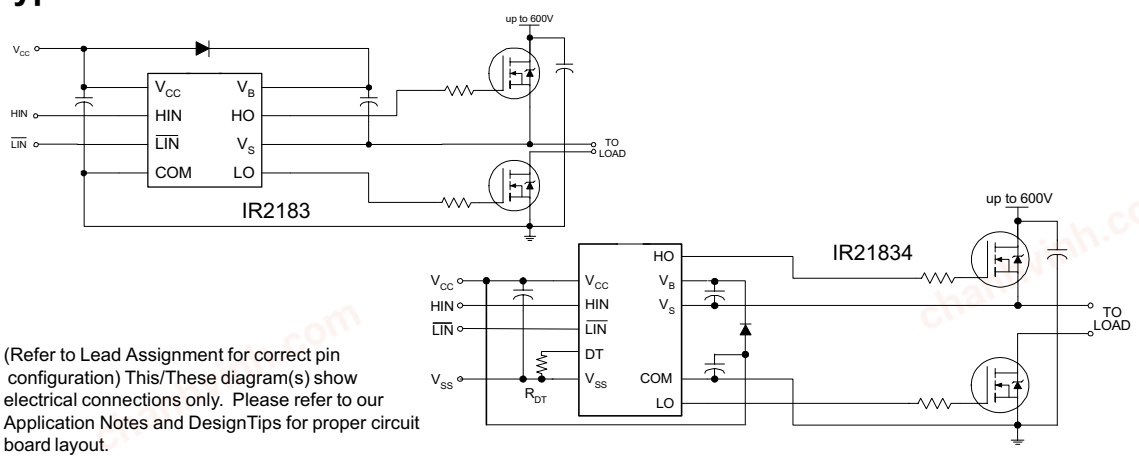
Description

The IR2183(4)(S) are high voltage, high speed power MOSFET and IGBT drivers with dependent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 volts.

IR2181/IR2183/IR2184 Feature Comparison

Part	Input logic	Cross-conduction prevention logic	Dead-Time	Ground Pins	Ton/Toff
2181	HIN/LIN	no	none	COM	180/220 ns
21814				VSS/COM	
2183	HIN/$\overline{\text{LIN}}$	yes	Internal 500ns	COM	180/220 ns
21834			Program 0.4 ~ 5 us	VSS/COM	
2184	IN/$\overline{\text{SD}}$	yes	Internal 500ns	COM	680/270 ns
21844			Program 0.4 ~ 5 us	VSS/COM	

Typical Connection



(Refer to Lead Assignment for correct pin configuration) This/These diagram(s) show electrical connections only. Please refer to our Application Notes and DesignTips for proper circuit board layout.

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Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition		Min.	Max.	Units
V_B	High side floating absolute voltage		-0.3	625	V
V_S	High side floating supply offset voltage		V_B - 25	V_B + 0.3	
V_{HO}	High side floating output voltage		V_S - 0.3	V_B + 0.3	
V_{CC}	Low side and logic fixed supply voltage		-0.3	25	
V_{LO}	Low side output voltage		-0.3	V_{CC} + 0.3	
DT	Programmable dead-time pin voltage (IR21834 only)		V_{SS} - 0.3	V_{CC} + 0.3	
V_{IN}	Logic input voltage (HIN & $\overline{LIN}$)		V_{SS} - 0.3	V_{SS} + 5	
V_{SS}	Logic ground (IR21834 only)		V_{CC} - 25	V_{CC} + 0.3	
dV_S/dt	Allowable offset supply voltage transient		—	50	V/ns
P_D	Package power dissipation @ $T_A \leq +25°C$	(8-lead PDIP)	—	1.0	W
		(8-lead SOIC)	—	0.625	
		(14-lead PDIP)	—	1.6	
		(14-lead SOIC)	—	1.0	
Rth_{JA}	Thermal resistance, junction to ambient	(8-lead PDIP)	—	125	°C/W
		(8-lead SOIC)	—	200	
		(14-lead PDIP)	—	75	
		(14-lead SOIC)	—	120	
T_J	Junction temperature		—	150	°C
T_S	Storage temperature		-50	150	
T_L	Lead temperature (soldering, 10 seconds)		—	300	

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The V_S and V_{SS} offset rating are tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
VB	High side floating supply absolute voltage	V_S + 10	V_S + 20	V
V_S	High side floating supply offset voltage	Note 1	600	
V_{HO}	High side floating output voltage	V_S	V_B	
V_{CC}	Low side and logic fixed supply voltage	10	20	
V_{LO}	Low side output voltage	0	V_{CC}	
V_{IN}	Logic input voltage (HIN & $\overline{LIN}$)	V_{SS}	V_{SS} + 4	
DT	Programmable dead-time pin voltage (IR21834 only)	V_{SS}	V_{CC}	
V_{SS}	Logic ground (IR21834 only)	-5	5	
T_A	Ambient temperature	-40	125	°C

Note 1: Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to -V_{BS}. (Please refer to the Design Tip DT97-3 for more details).

Note 2: HIN and $\overline{LIN}$ pins are internally clamped with a 5.2V zener diode.

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Dynamic Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 15V, V_{SS} = COM, C_L = 1000 pF, T_A = 25°C, DT = VSS unless otherwise specified.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t_{on}	Turn-on propagation delay	—	180	270	nsec	V_S = 0V
t_{off}	Turn-off propagation delay	—	220	330		V_S = 0V or 600V
MT	Delay matching $\lvert t_{on} - t_{off} \rvert$	—	0	35		
t_r	Turn-on rise time	—	40	60		V_S = 0V
t_f	Turn-off fall time	—	20	35		V_S = 0V
DT	Deadtime: LO turn-off to HO turn-on(DT_{LO-HO}) &	280	400	520		RDT= 0
	HO turn-off to LO turn-on (DT_{HO-LO})	4	5	6	µsec	RDT = 200k (IR21834)
MDT	Deadtime matching = $\lvert DT_{LO-HO} - DT_{HO-LO} \rvert$	—	0	50	nsec	RDT=0
		—	0	600		RDT = 200k (IR21834)

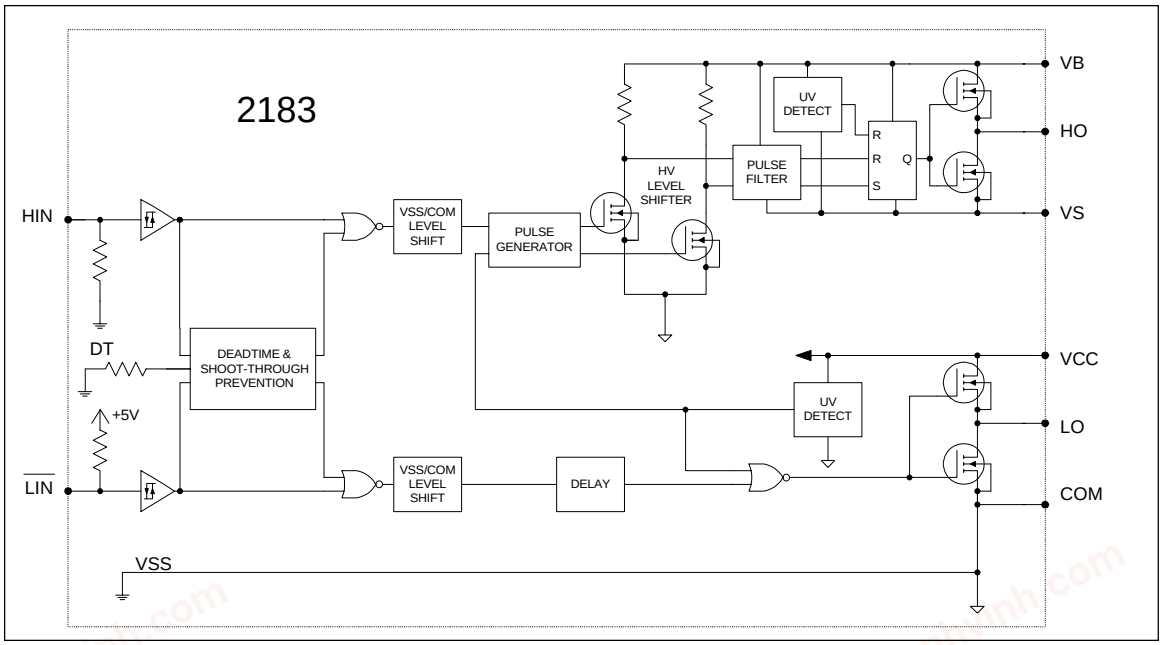
Static Electrical Characteristics

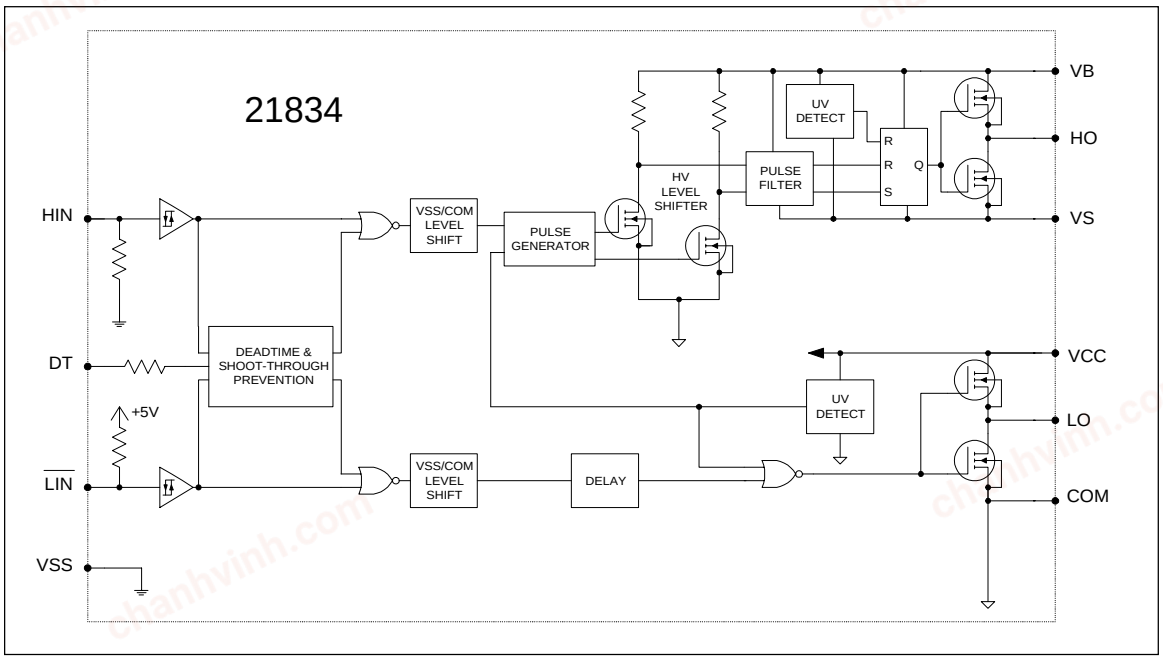
V_{BIAS} (V_{CC}, V_{BS}) = 15V, V_{SS} = COM, DT= V_{SS} and T_A = 25°C unless otherwise specified. The V_{IL}, V_{IH} and I_{IN} parameters are referenced to V_{SS}/COM and are applicable to the respective input leads: HIN and $\overline{LIN}$. The V_O, I_O and Ron parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V_{IH}	Logic “1” input voltage for HIN & logic “0” for $\overline{LIN}$	2.7	—	—	V	V_{CC} = 10V to 20V
V_{IL}	Logic “0” input voltage for HIN & logic “1” for $\overline{LIN}$	—	—	0.8		V_{CC} = 10V to 20V
V_{OH}	High level output voltage, V_{BIAS} - V_O	—	—	1.2		I_O = 0A
V_{OL}	Low level output voltage, V_O	—	—	0.1		I_O = 0A
I_{LK}	Offset supply leakage current	—	—	50	µA	V_B = V_S = 600V
I_{QBS}	Quiescent V_{BS} supply current	20	60	150		V_{IN} = 0V or 5V
I_{QCC}	Quiescent V_{CC} supply current	0.4	1.0	1.6	mA	V_{IN} = 0V or 5V
I_{IN+}	Logic “1” input bias current	—	25	60	µA	HIN = 5V, $\overline{LIN}$ = 0V
I_{IN-}	Logic “0” input bias current	—	—	1.0		HIN = 0V, $\overline{LIN}$ = 5V
V_{CCUV+} V_{BSUV+}	V_{CC} and V_{BS} supply undervoltage positive going threshold	8.0	8.9	9.8	V	
V_{CCUV-} V_{BSUV-}	V_{CC} and V_{BS} supply undervoltage negative going threshold	7.4	8.2	9.0		
V_{CCUVH} V_{BSUVH}	Hysteresis	0.3	0.7	—		
I_{O+}	Output high short circuit pulsed current	1.4	1.9	—	A	V_O = 0V, PW ≤ 10 µs
I_{O-}	Output low short circuit pulsed current	1.8	2.3	—		V_O = 15V, PW ≤ 10 µs

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Functional Block Diagrams



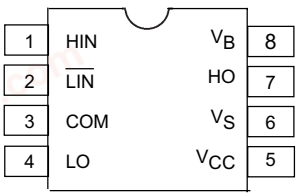


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Lead Definitions

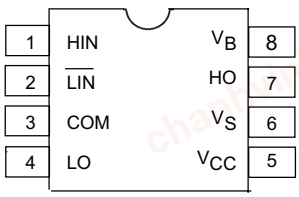
Symbol	Description
HIN	Logic input for high side gate driver output (HO), in phase (referenced to COM for IR2183 and VSS for IR21834)
$\overline{LIN}$	Logic input for low side gate driver output (LO), out of phase (referenced to COM for IR2183 and VSS for IR21834)
DT	Programmable dead-time lead, referenced to VSS. (IR21834 only)
VSS	Logic Ground (21834 only)
V_B	High side floating supply
HO	High side gate driver output
V_S	High side floating supply return
V_{CC}	Low side and logic fixed supply
LO	Low side gate driver output
COM	Low side return

Lead Assignments



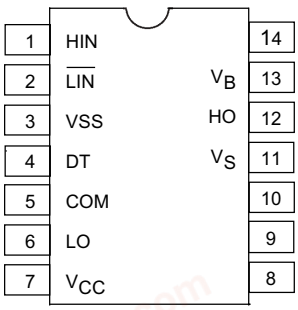
8-Lead PDIP

IR2183



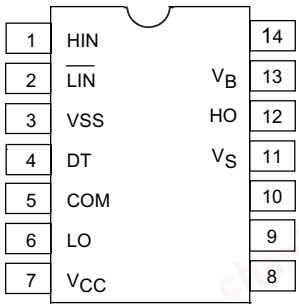
8-Lead SOIC

IR2183S



14-Lead PDIP

IR21834



14-Lead SOIC

IR21834S

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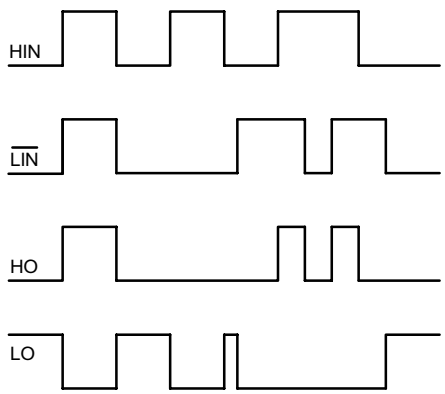


Figure 1. Input/Output Timing Diagram

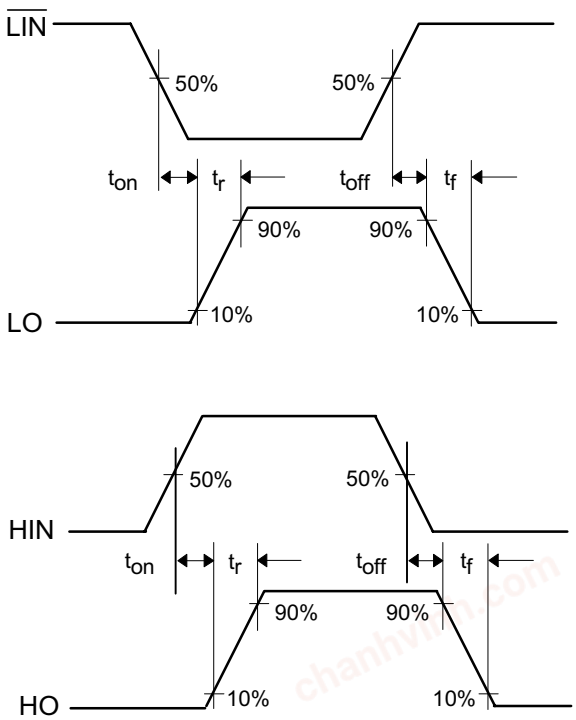


Figure 2. Switching Time Waveform Definitions

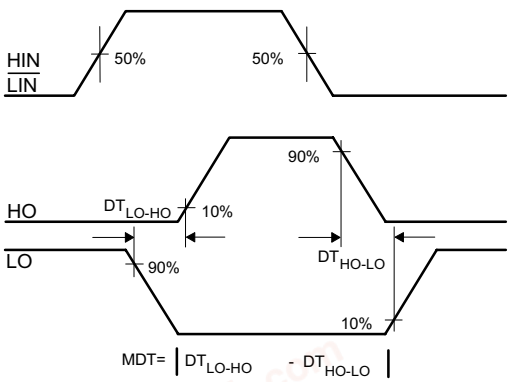


Figure 3. Deadtime Waveform Definitions

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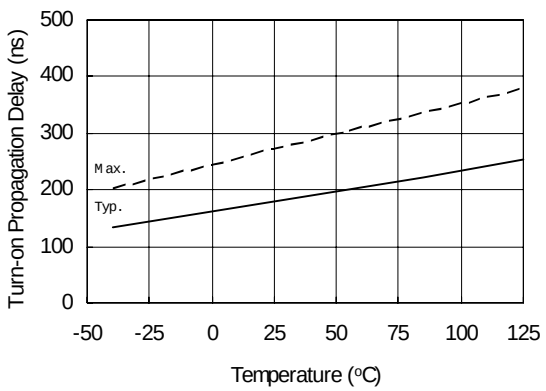


Figure 4A. Turn-on Propagation Delay vs. Temperature

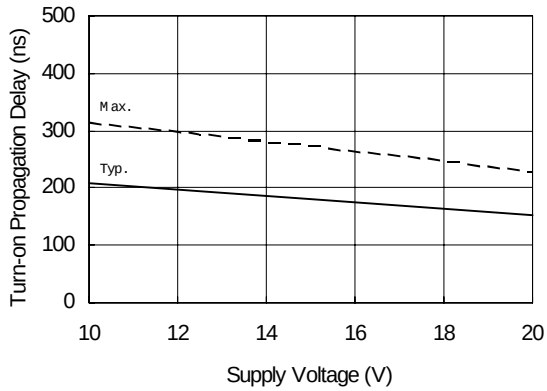


Figure 4B. Turn-on Propagation Delay vs. Supply Voltage

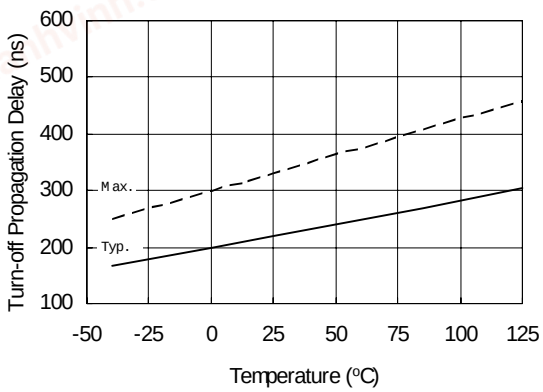


Figure 5A. Turn-off Propagation Delay vs. Temperature

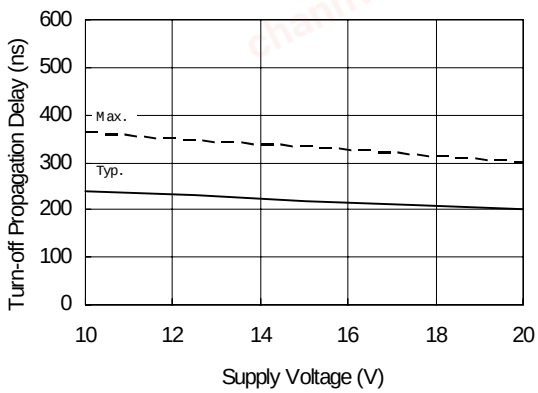


Figure 5B. Turn-off Propagation Delay vs. Supply Voltage

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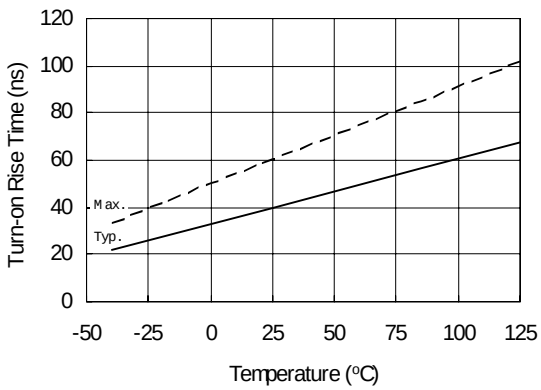


Figure 6A. Turn-on Rise Time vs. Temperature

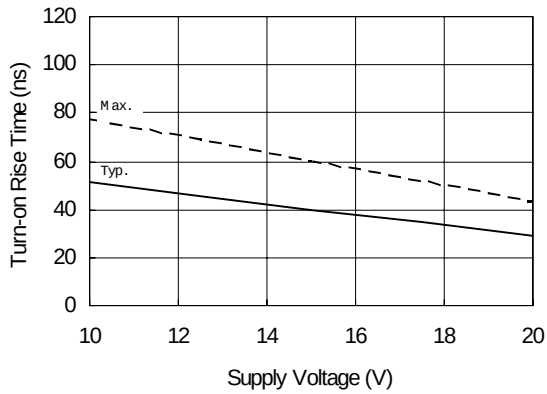


Figure 6B. Turn-on Rise Time vs. Supply Voltage

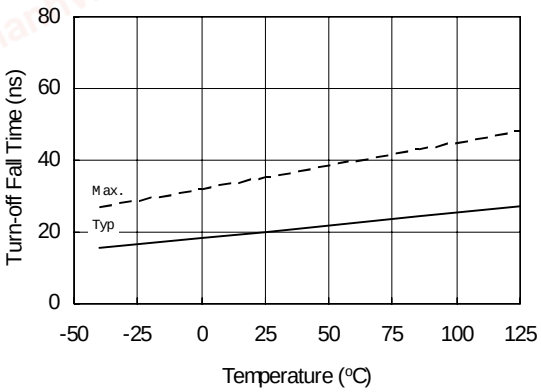


Figure 7A. Turn-off Fall Time vs. Temperature

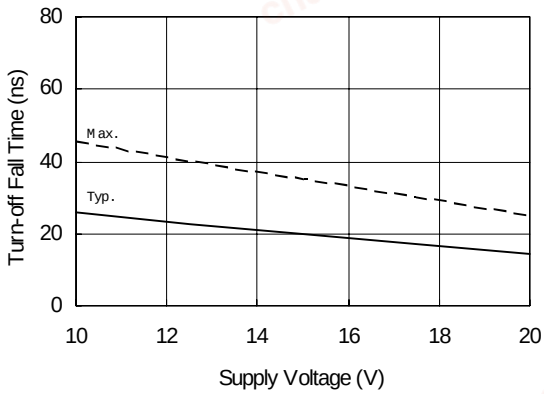


Figure 7B. Turn-off Fall Time vs. Supply Voltage

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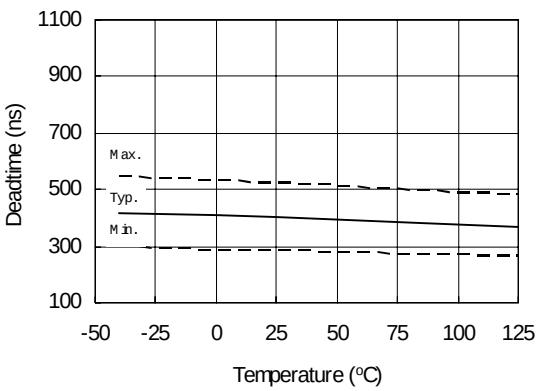


Figure 8A. Deadtime vs. Temperature

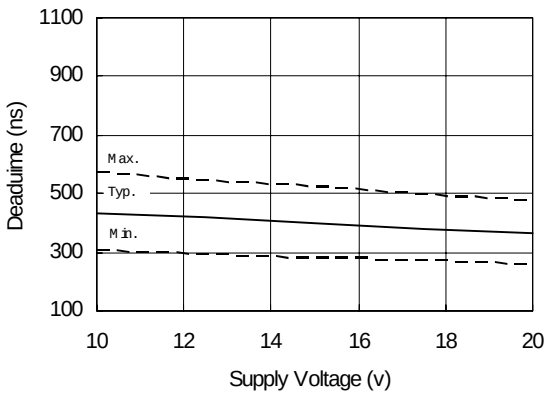


Figure 8B. Deadtime vs. Supply Voltage

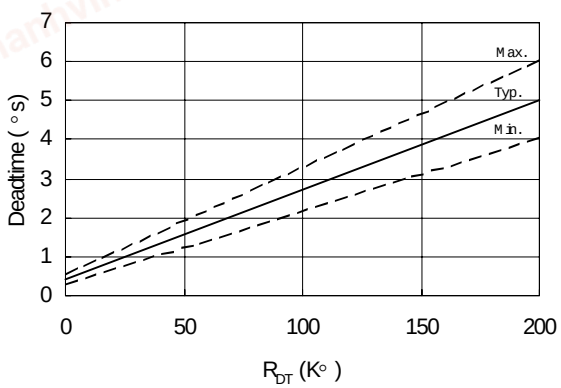


Figure 8C. Deadtime vs. R_{DT}

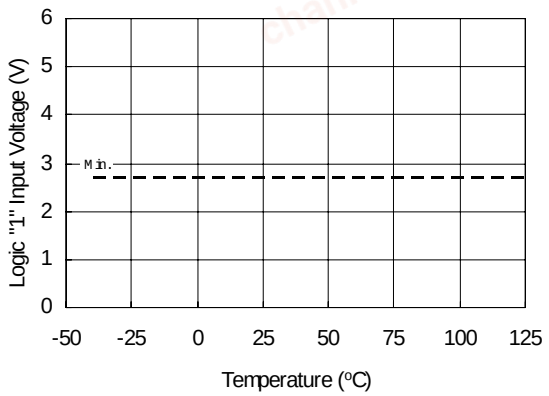


Figure 9A. Logic "1" Input Voltage vs. Temperature

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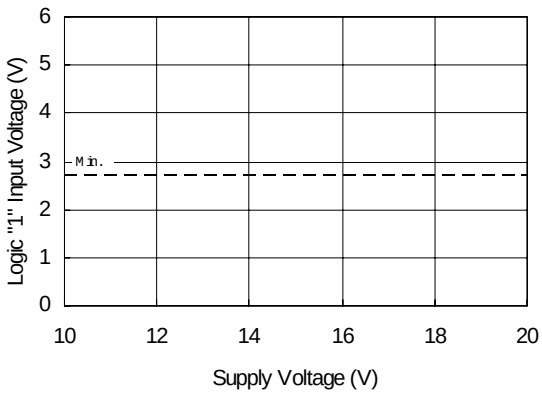


Figure 9B. Logic "1" Input Voltage vs. Supply Voltage

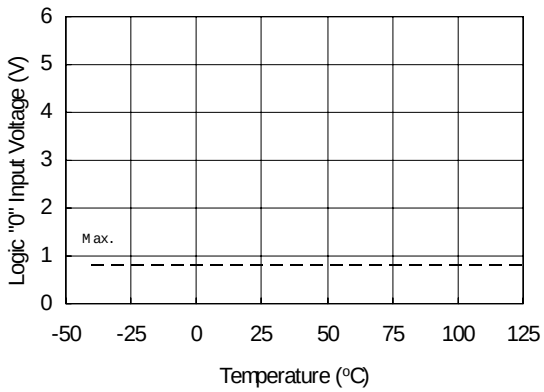


Figure 10A. Logic "0" Input Voltage vs. Temperature

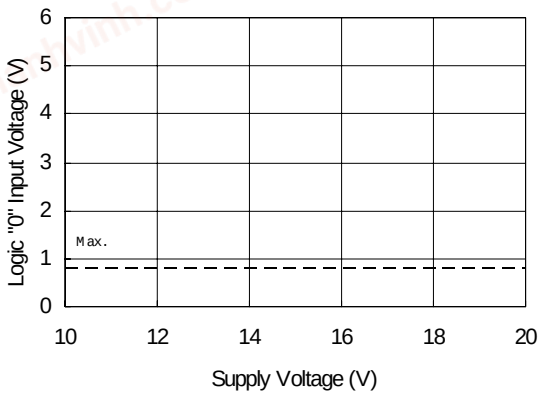


Figure 10B. Logic "0" Input Voltage vs. Supply Voltage

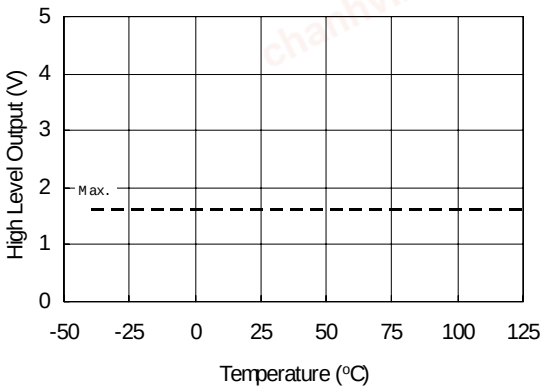


Figure 11A. High Level Output vs. Temperature

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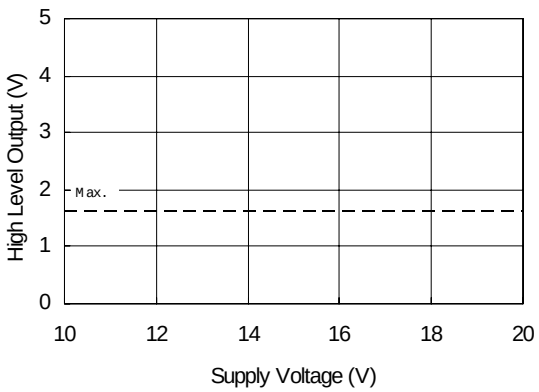


Figure 11B. High Level Output vs. Supply Voltage

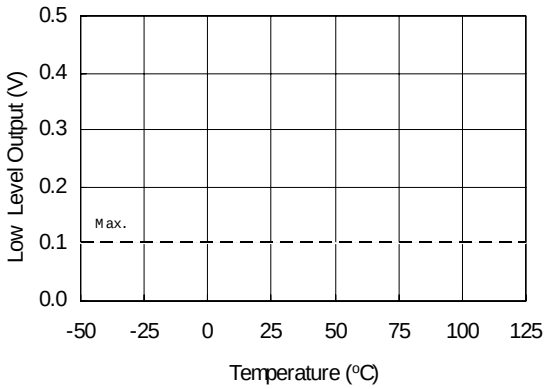


Figure 12A. Low Level Output vs. Temperature

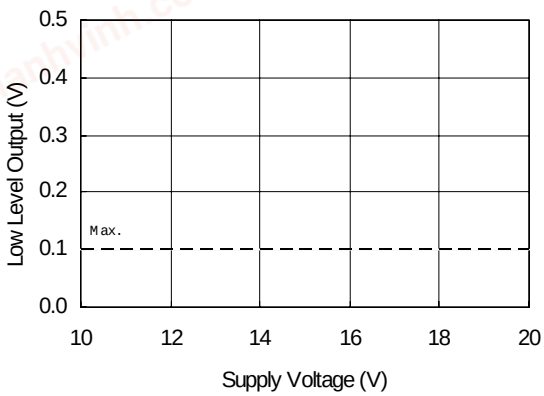


Figure 12B. Low Level Output vs. Supply Voltage

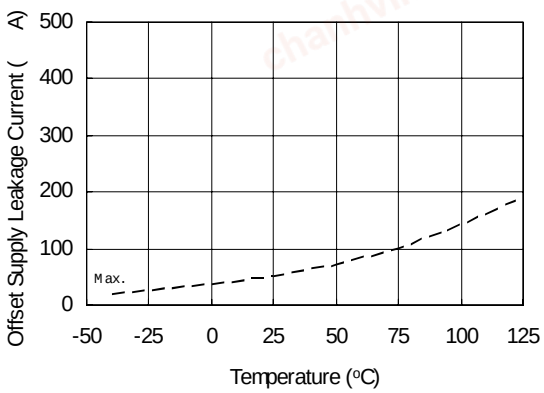


Figure 13A. Offset Supply Leakage Current vs. Temperature

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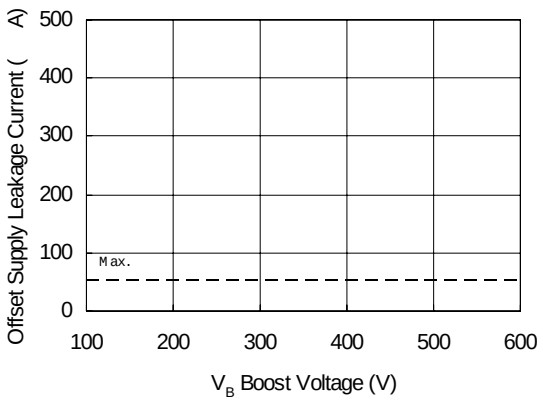


Figure 13B. Offset Supply Leakage Current vs. V_B Boost Voltage

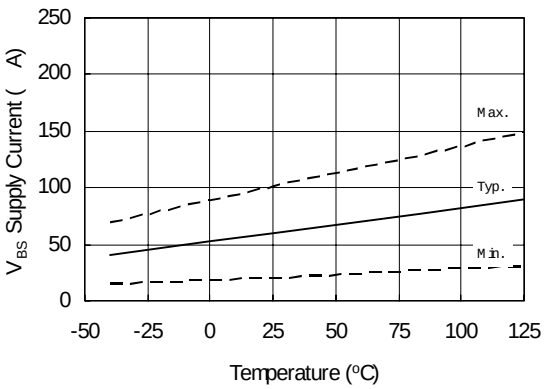


Figure 14A. V_{BS} Supply Current vs. Temperature

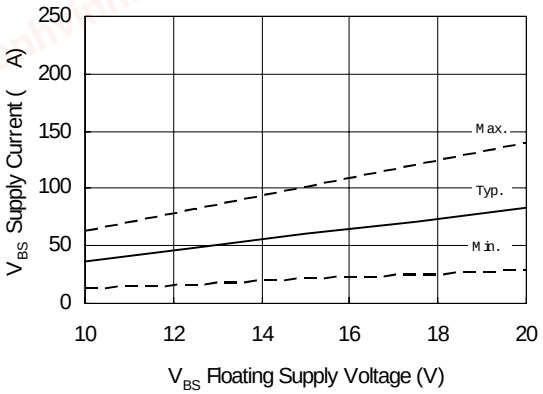


Figure 14B. V_{BS} Supply Current vs. V_{BS} Floating Supply Voltage

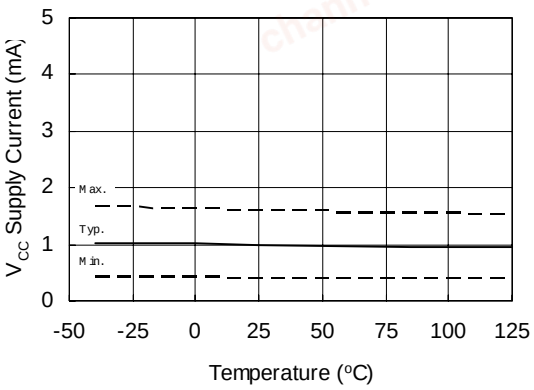


Figure 15A. V_{CC} Supply Current vs. Temperature

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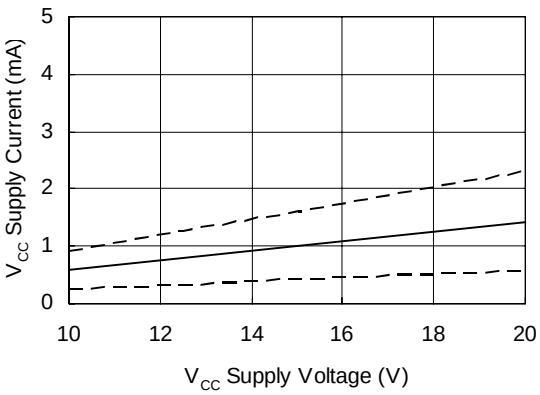


Figure 15B. V_{CC} Supply Current vs. V_{CC} Supply Voltage

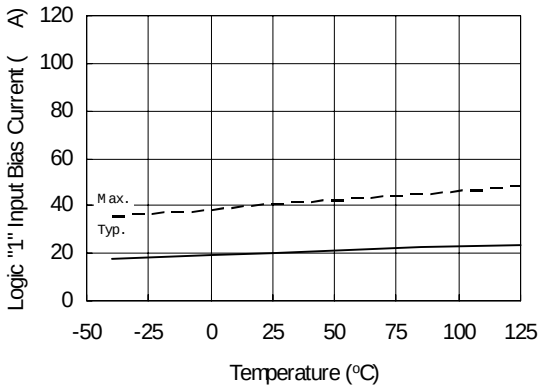


Figure 16A. Logic "1" Input Bias Current vs. Temperature

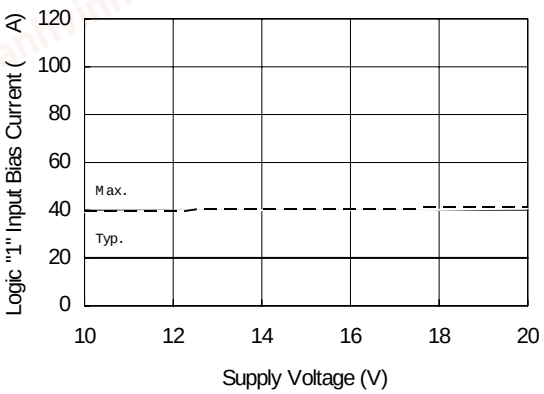


Figure 16B. Logic "1" Input Bias Current vs. Supply Voltage

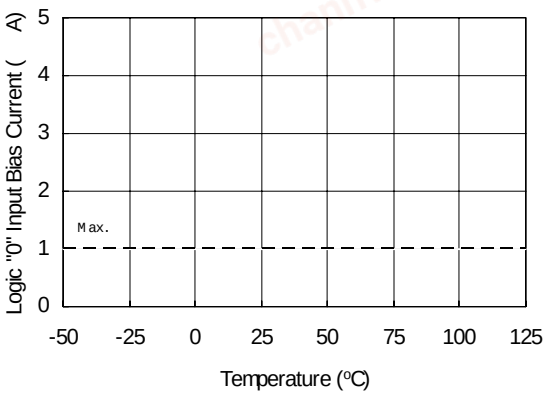


Figure 17A. Logic "0" Input Bias Current vs. Temperature

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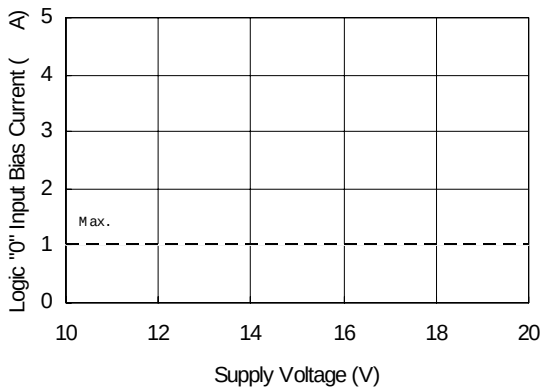


Figure 17B. Logic "0" Input Bias Current vs. Supply Voltage

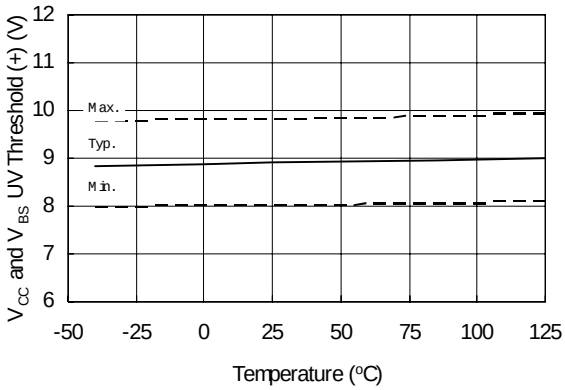


Figure 18. V_{CC} and V_{BS} Undervoltage Threshold (+) vs. Temperature

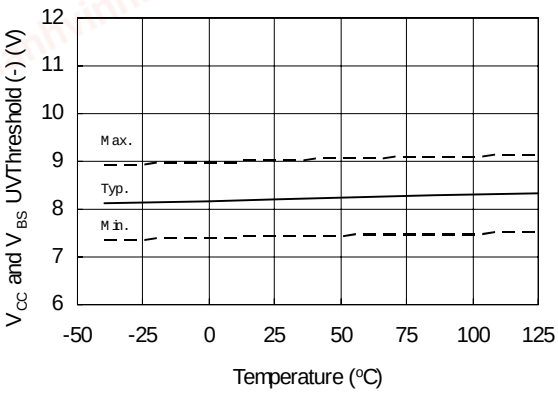


Figure 19. V_{CC} and V_{BS} Undervoltage Threshold (-) vs. Temperature

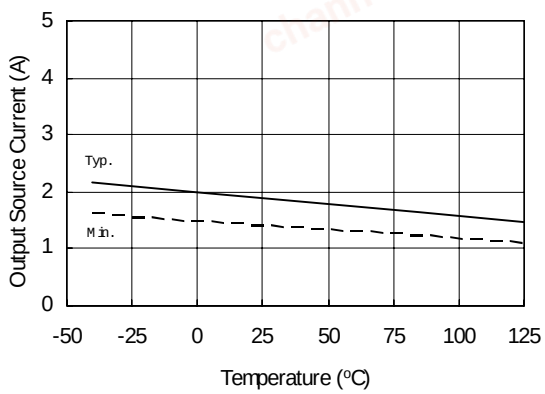


Figure 20A. Output Source Current vs. Temperature

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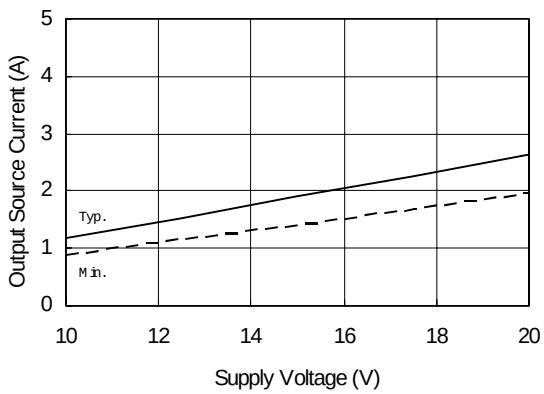


Figure 20B. Output Source Current vs. Supply Voltage

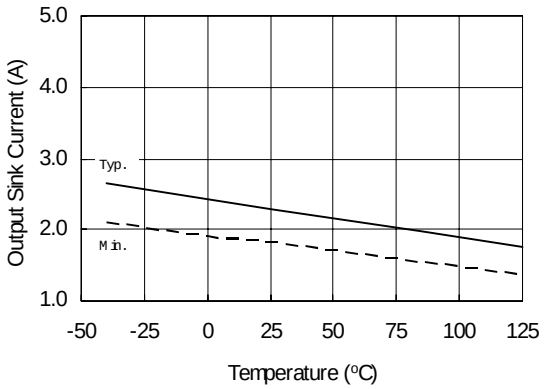


Figure 21A. Output Sink Current vs. Temperature

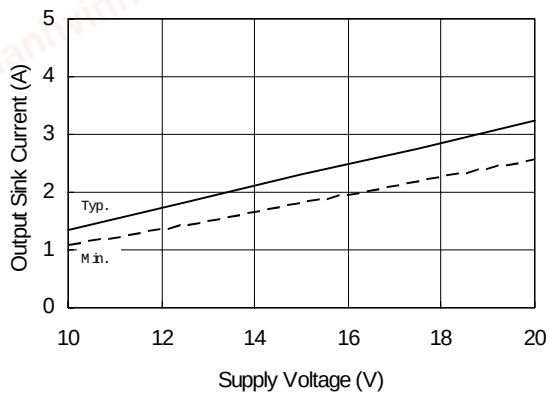


Figure 21B. Output Sink Current vs. Supply Voltage

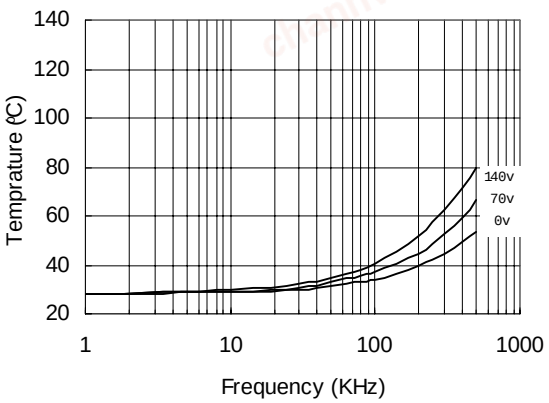


Figure 22. IR2183 vs. Frequency (IRFBC20), R_{gate}=33Ω, V_{CC}=15V

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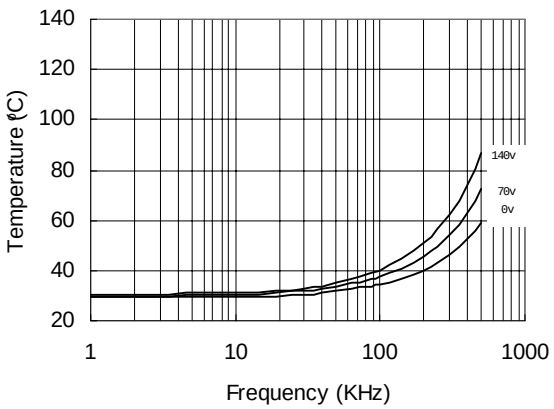


Figure 23. IR2183 vs. Frequency (IRFBC30), R_{gate}=22Ω, V_{CC}=15V

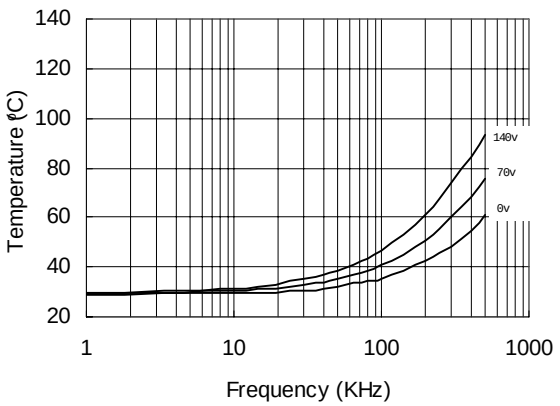


Figure 24. IR2183 vs. Frequency (IRFBC40), R_{gate}=15Ω, V_{CC}=15V

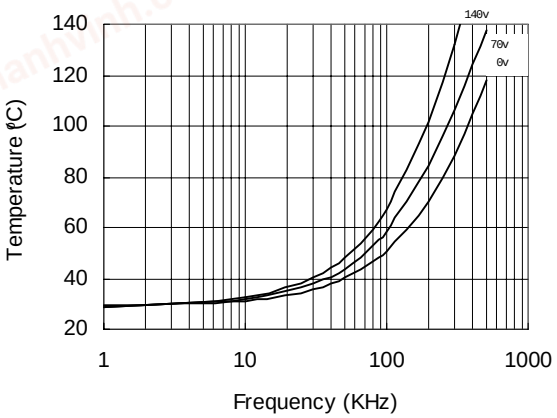


Figure 25. IR2183 vs. Frequency (IRFPE50), R_{gate}=10Ω, V_{CC}=15V

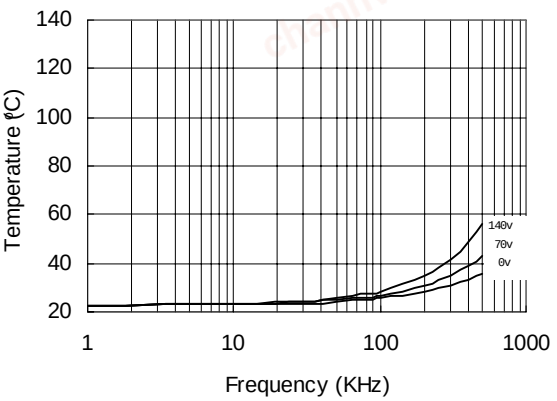


Figure 26. IR21834 vs. Frequency (IRFBC20), R_{gate}=33Ω, V_{CC}=15V

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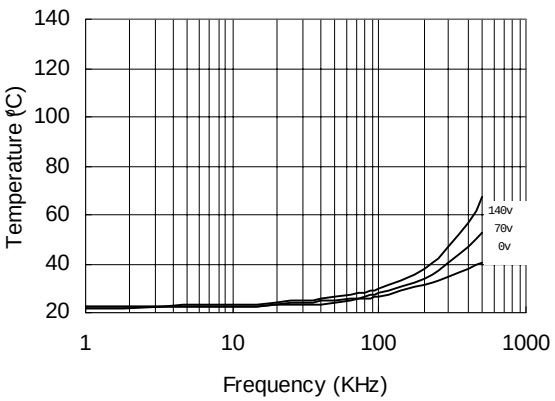


Figure 27. IR21834 vs. Frequency (IRFBC30), R_{gate}=22Ω, V_{CC}=15V

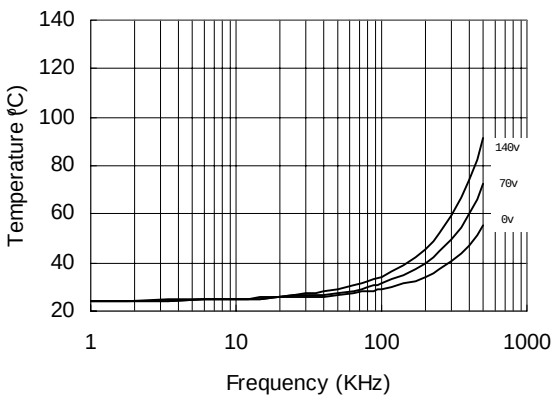


Figure 28. IR21834 vs. Frequency (IRFBC40), R_{gate}=15Ω, V_{CC}=15V

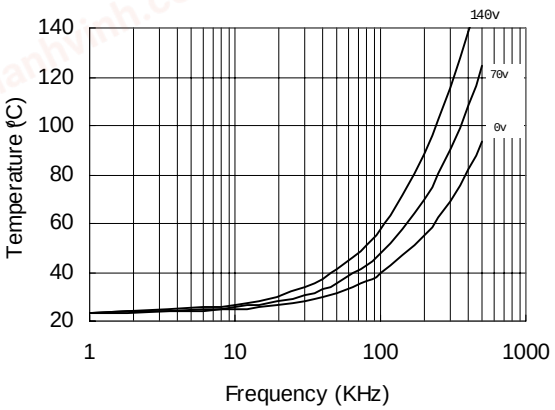


Figure 29. IR21834 vs. Frequency (IRFPE50), R_{gate}=10Ω, V_{CC}=15V

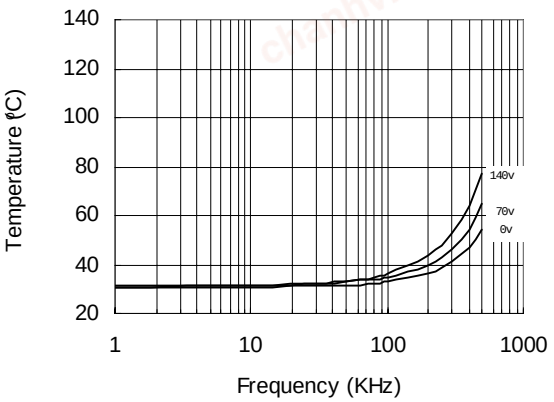


Figure 30. IR2183s vs. Frequency (IRFBC20), R_{gate}=33Ω, V_{CC}=15V

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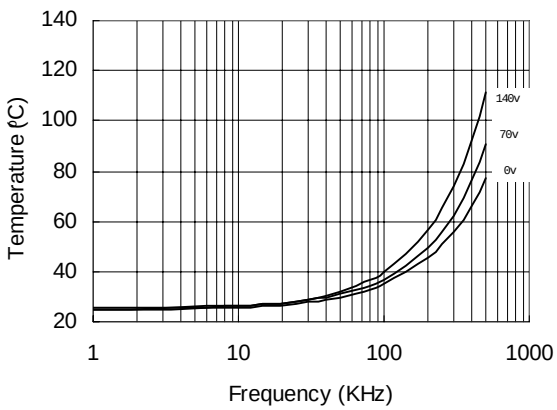


Figure 31. IR2183s vs. Frequency (IRFBC30), R_{gate}=22Ω, V_{CC}=15V

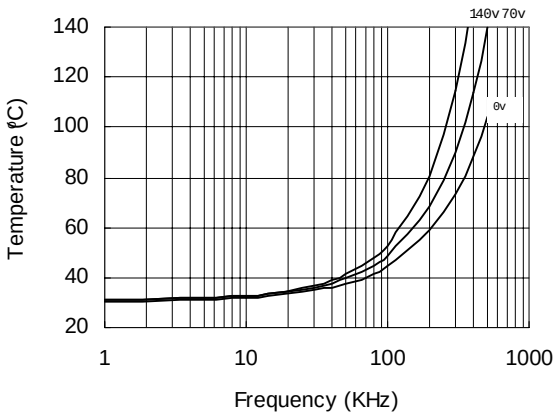


Figure 32. IR2183s vs. Frequency (IRFBC40), R_{gate}=15Ω, V_{CC}=15V

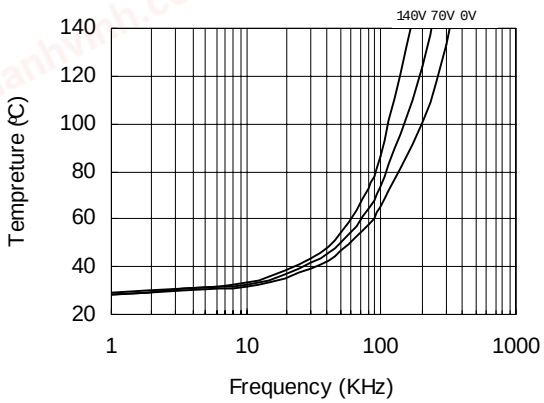


Figure 33. IR2183s vs. Frequency (IRFPE50), R_{gate}=10Ω, V_{CC}=15V

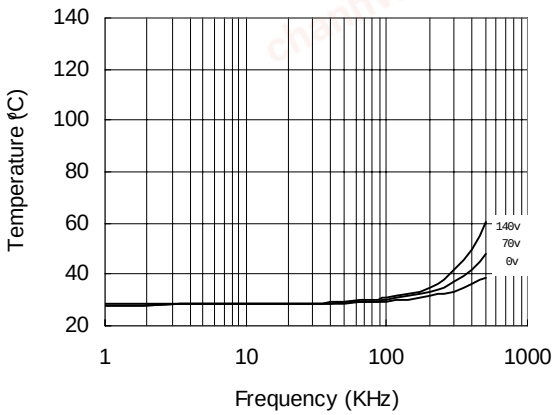


Figure 34. IR21834s vs. Frequency (IRFBC20), R_{gate}=33Ω, V_{CC}=15V

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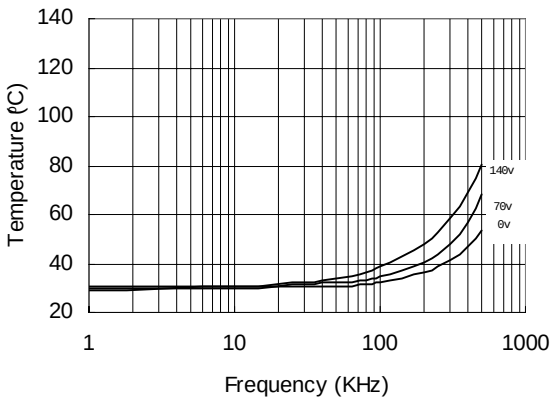


Figure 35. IR21834s vs. Frequency (IRFBC30), R_{gate}=22Ω, V_{CC}=15V

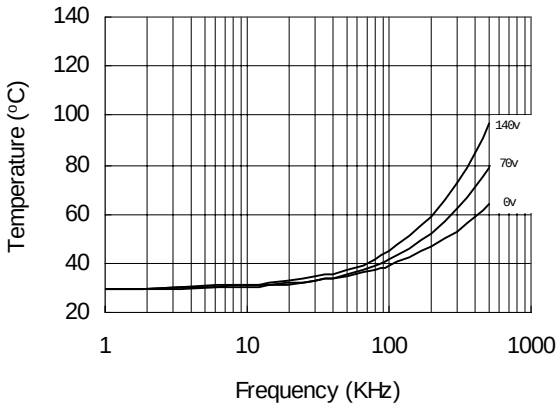


Figure 36. IR21834s vs. Frequency (IRFBC40), R_{gate}=15Ω, V_{CC}=15V

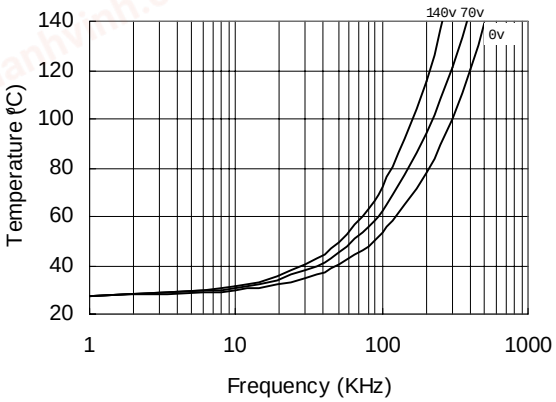
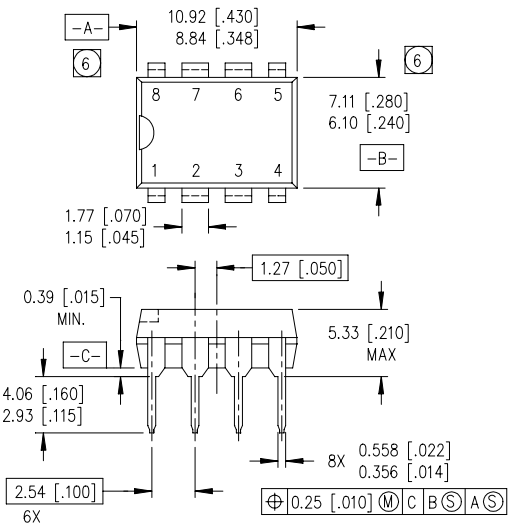


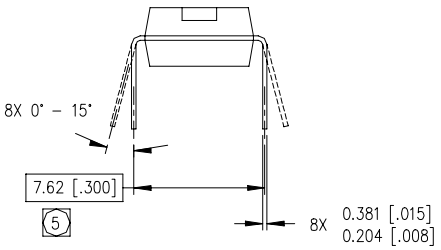
Figure 37. IR21834s vs. Frequency (IRFPE50), R_{gate}=10Ω, V_{CC}=15V

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Case outlines

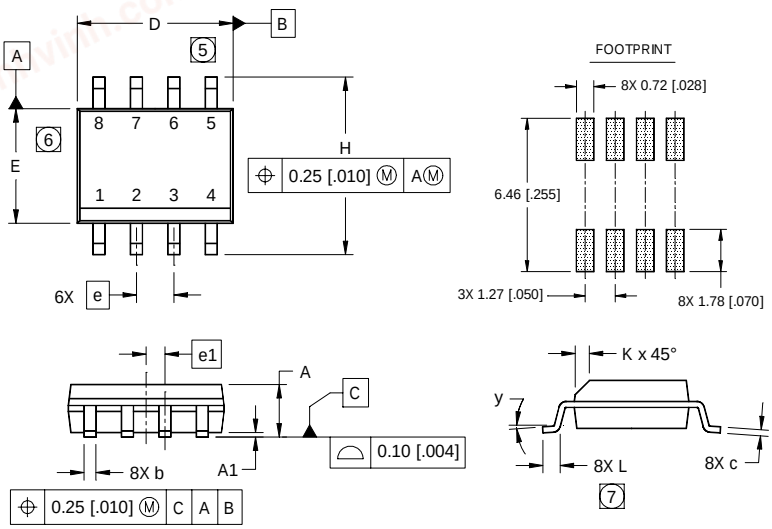


NOTES:
1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M–1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS–001AB.
5. MEASURED WITH THE LEADS CONSTRAINED TO BE PERPENDICULAR TO DATUM PLANE C.
6. DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.25 [.010].



8-Lead PDIP

01-6014
01-3003 01 (MS-001AB)



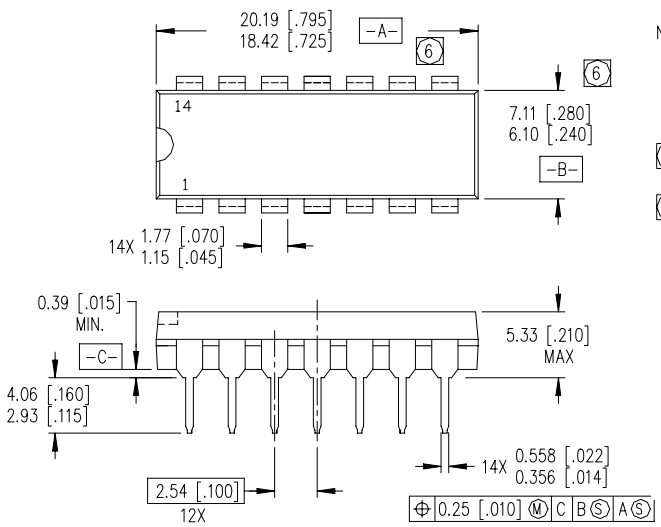
DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.0532	.0688	1.35	1.75
A1	.0040	.0098	0.10	0.25
b	.013	.020	0.33	0.51
c	.0075	.0098	0.19	0.25
D	.189	.1968	4.80	5.00
E	.1497	.1574	3.80	4.00
e	.050 BASIC		1.27 BASIC	
e 1	.025 BASIC		0.635 BASIC	
H	.2284	.2440	5.80	6.20
K	.0099	.0196	0.25	0.50
L	.016	.050	0.40	1.27
y	0°	8°	0°	8°

NOTES:
1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
5. DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 [.006].
6. DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 [.010].
7. DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.

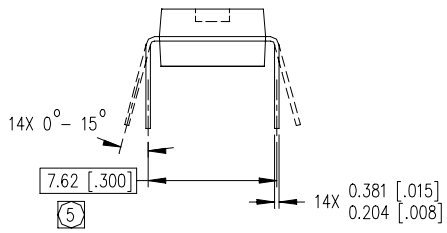
8-Lead SOIC

01-6027
01-0021 11 (MS-012AA)

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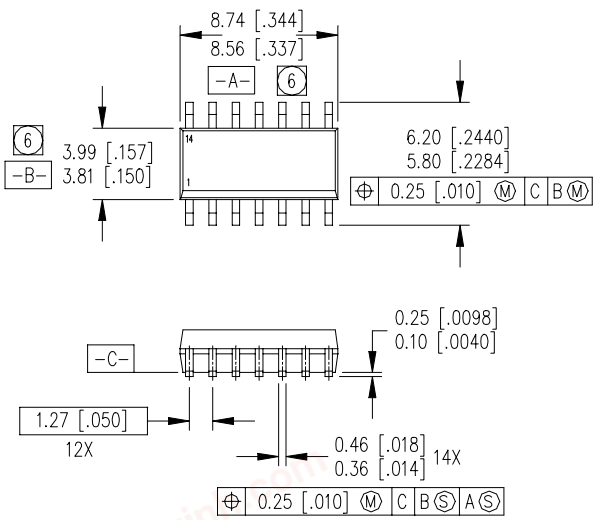


NOTES:
1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M–1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS–001AC.
5. MEASURED WITH THE LEADS CONSTRAINED TO BE PERPENDICULAR TO DATUM PLANE C.
6. DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.25 [.010].

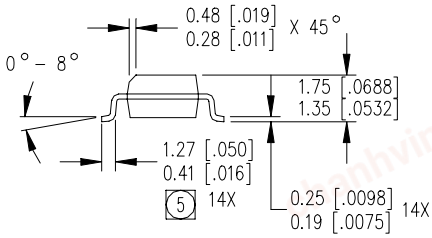


14-Lead PDIP

01-6010
01-3002 03 (MS-001AC)



NOTES:
1 DIMENSIONING & TOLERANCING PER ANSI Y14.5M–1982.
2 CONTROLLING DIMENSION: MILLIMETER
3 DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4 OUTLINE CONFORMS TO JEDEC OUTLINE MS–012AB.
5 DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.
6 DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.15 [.006].

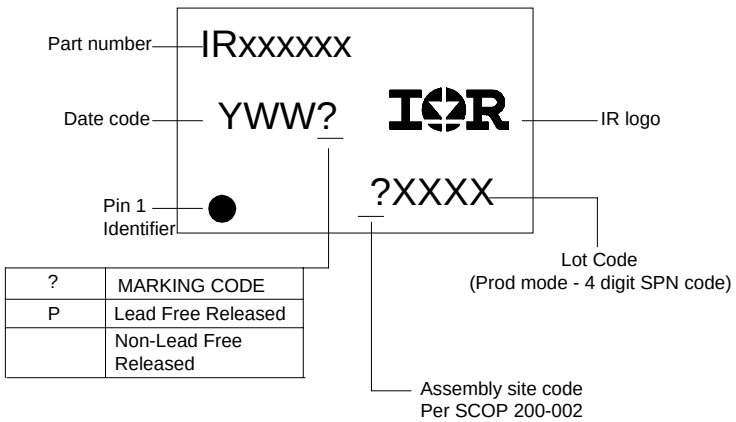


14-Lead SOIC (narrow body)

01-6019
01-3063 00 (MS-012AB)

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LEADFREE PART MARKING INFORMATION



?	MARKING CODE
P	Lead Free Released
	Non-Lead Free Released

ORDER INFORMATION

Basic Part (Non-Lead Free)
8-Lead PDIP IR2183 order IR2183
8-Lead SOIC IR2183S order IR2183S
14-Lead PDIP IR21834 order IR21834
14-Lead SOIC IR21834 order IR21834S

Leadfree Part
8-Lead PDIP IR2183 order IR2183PbF
8-Lead SOIC IR2183S order IR2183SPbF
14-Lead PDIP IR21834 order IR21834PbF
14-Lead SOIC IR21834 order IR21834SPbF

Thisproduct has been designed and qualified for the industrial market.
Qualification Standards can be found on IR's Web Site *http://www.irf.com*
Data and specifications subject to change without notice.
IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 Tel: (310) 252-7105
4/4/2006